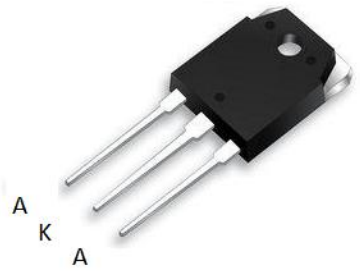
MUR3060PT

Ultra-Fast Recovery Diodes 15A*2 FRED Pt

Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

TO-3P

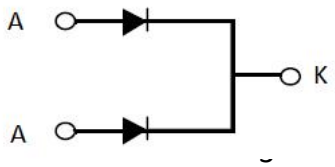


Typical Applications

- Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package**: TO-3P
  Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity**: As marked



	V_{RSM} V	V_{RRM} V
MUR3060PT	600	600

■Maximum Ratings (Tj=25℃ Unless otherwise specified)

Symbol	Test Conditions		Maximum Ratings	Unit
I_{FRMS} I_{FAVM} I_{FRM}	$T_{VJ}=T_{VJM}$ $T_C=100^oC$; rectangular, d=0.5 t_p<10us; rep. rating, pulse width limited by T_{VJM}		25 30 150	A
I_{FSM}	$T_{VJ}=45^oC$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	100 110	A
	$T_{VJ}=150^oC$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	85 95	
I^2t	$T_{VJ}=45^oC$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	50 50	A^2s
	$T_{VJ}=150^oC$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	36 37	
T_{VJ} T_{VJM} T_{stg}			-40...+150 150 -40...+150	^oC
P_{tot}	$T_C=25^oC$		62	W
M_d	Mounting torque		0.4...0.6	Nm
Weight	typical		6	g

MUR3060PT

Ultra-Fast Recovery Diodes 15A*2 FRED Pt

■Electrical Characteristics（Tj=25℃ Unless otherwise specified）

Symbol	Test Conditions	Characteristic Values typ.	Characteristic Values max.	Unit
I_R	T_{VJ}=25°C; V_R=V_{RRM} T_{VJ}=25°C; V_R=0.8·V_{RRM} T_{VJ}=125°C; V_R=0.8·V_{RRM}		50 25 3	uA uA mA
V_F	I_F=15A; T_{VJ}=150°C T_{VJ}=25°C		1.5 1.7	V
V_{TO}	For power-loss calculations only		1.12	V
r_T	T_{VJ}=T_{VJM}		23.2	mΩ
R_{thJC} R_{thCK} R_{thJA}		0.5	2 60	K/W
t_{rr}	I_F=1A; -di/dt=50A/us; V_R=30V; T_{VJ}=25°C	35	50	ns
I_{RM}	V_R=350V; I_F=15A; -di$_F$/dt=100A/us; L≤0.05uH; T_{VJ}=100°C	4	4.4	A

■Thermal Characteristics （T_a=25℃ Unless otherwise specified）

PARAMETER		SYMBOL	UNIT	MUR3060PT
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	℃/W	1.0
	Between junction and Air	$R_{\theta J-A}$	℃/W	50

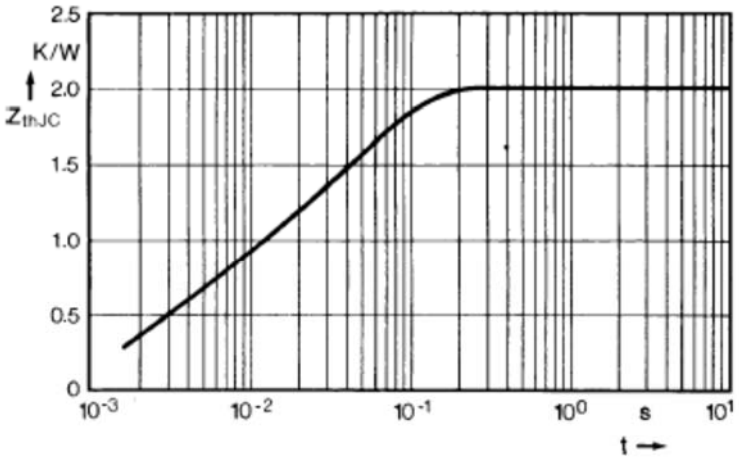


Fig. 7 Transient thermal impedance junction to case.

MUR3060PT

Ultra-Fast Recovery Diodes 15A*2 FRED Pt

■ **Characteristics**(Typical)

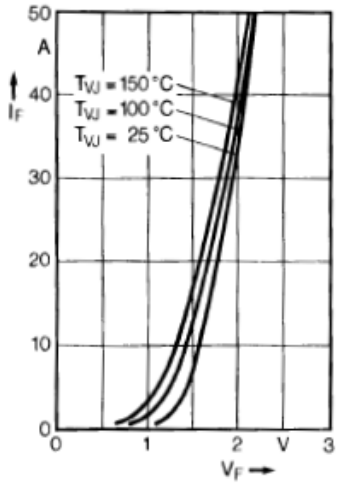


Fig. 1 Forward current versus voltage drop.

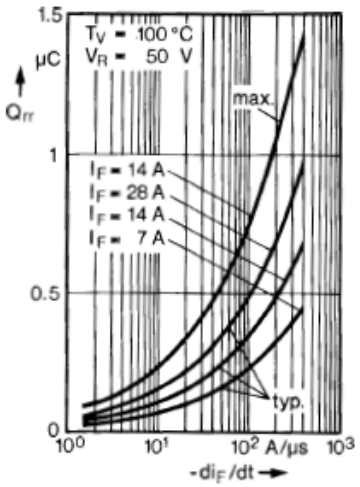


Fig. 2 Recovery charge versus $-di_F/dt$.

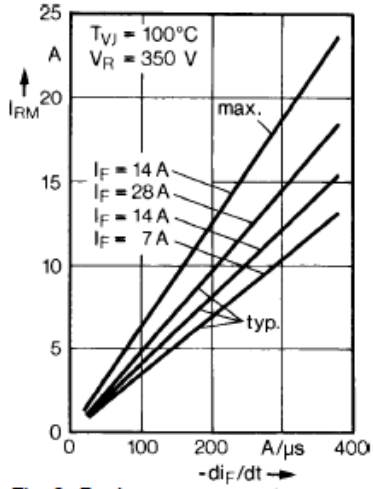


Fig. 3 Peak reverse current versus $-di_F/dt$.

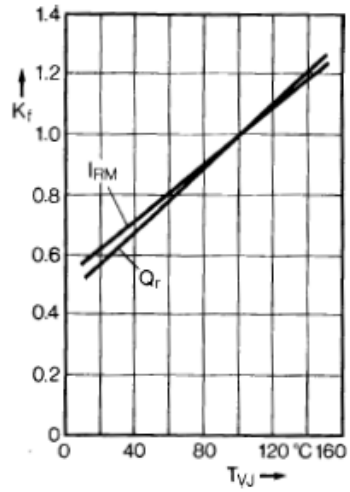


Fig. 4 Dynamic parameters versus junction temperature.

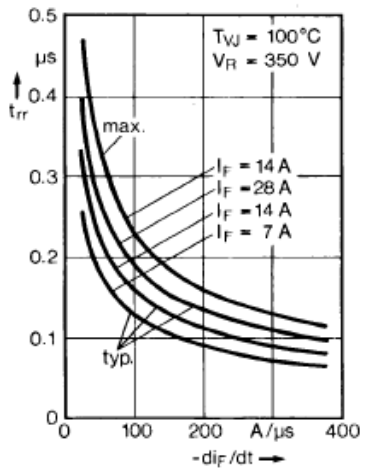


Fig. 5 Recovery time versus $-di_F/dt$.

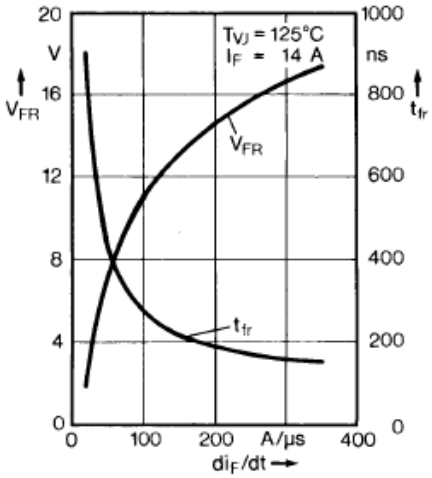
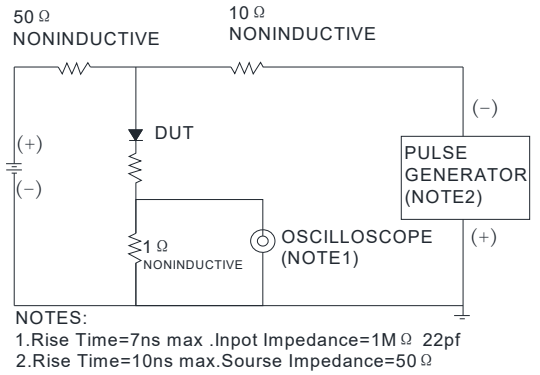
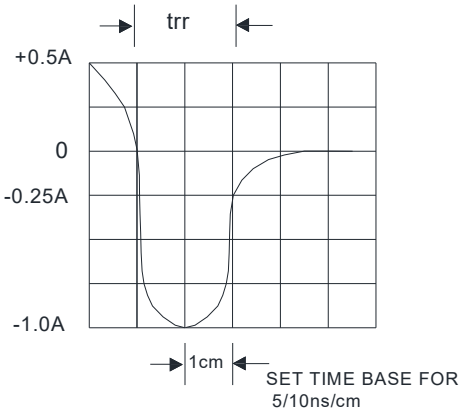


Fig. 6 Peak forward voltage versus di_F/dt.

FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



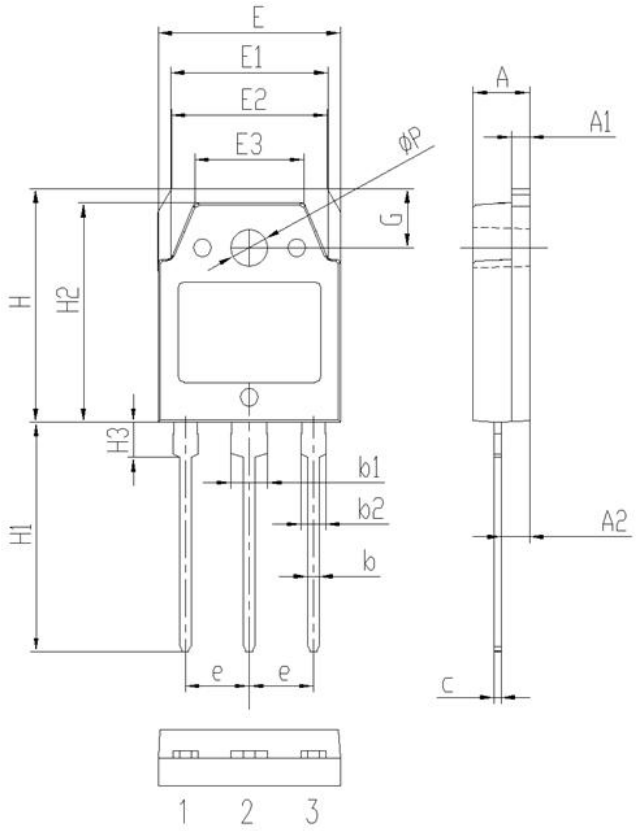


MUR3060PT

Ultra-Fast Recovery Diodes 15A*2 FRED Pt

■ Outline Dimensions

TO-3P



Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.60	5.00
A1	1.30	1.70
A2	2.20	2.60
b	0.80	1.20
b1	2.90	3.30
b2	1.90	2.30
c	0.40	0.80
e	5.25	5.65
E	15.3	15.7
E1	13.2	13.6
E2	13.1	13.5
E3	9.10	9.50
H	19.7	20.1
H1	19.1	20.1
H2	18.3	18.7
H3	2.80	3.20
G	4.80	5.20
ΦP	3.00	3.40